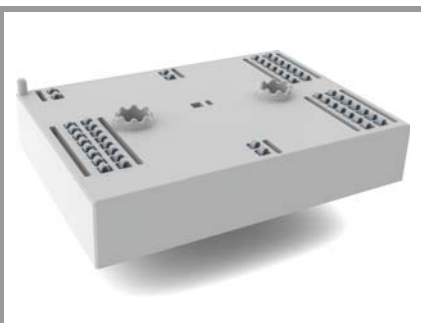


# SKiiP 36GB17E4V1



MiniSKiiP® 3 Dual

## Half-Bridge

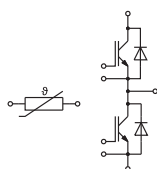
### SKiiP 36GB17E4V1

#### Features\*

- Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532
- NTC T-Sensor

#### Remarks

- Max. case temperature limited to  $T_C=125^\circ\text{C}$
- Product reliability results valid for  $T_j \leq 150^\circ\text{C}$  (recommended  $T_{j,op} = -40 \dots +150^\circ\text{C}$ )

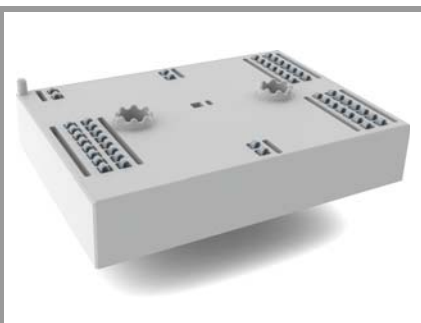


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Absolute Maximum Ratings			
Symbol	Conditions	Values	Unit
<b>Inverter - IGBT</b>			
$V_{CES}$	$T_j = 25^\circ\text{C}$	1700	V
$I_C$	$T_j = 175^\circ\text{C}$	$T_s = 25^\circ\text{C}$	224
		$T_s = 70^\circ\text{C}$	182
$I_{Cnom}$		200	A
$I_{CRM}$		600	A
$V_{GES}$		-20 ... 20	V
$t_{psc}$	$V_{CC} = 1000\text{ V}$ $V_{GE} \leq 15\text{ V}$ $V_{CES} \leq 1700\text{ V}$	$T_j = 150^\circ\text{C}$	10
$T_j$		-40 ... 175	$^\circ\text{C}$
<b>Inverse - Diode</b>			
$I_F$	$T_j = 175^\circ\text{C}$	$T_s = 25^\circ\text{C}$	193
		$T_s = 70^\circ\text{C}$	152
$I_{FRM}$		400	A
$I_{FSM}$	10 ms, sin 180°, $T_j = 150^\circ\text{C}$	1044	A
$T_j$		-40 ... 175	$^\circ\text{C}$
<b>Module</b>			
$I_{t(RMS)}$	$T_{terminal} = 80^\circ\text{C}$ , 20 A per spring	280	A
$T_{stg}$	module without TIM	-40 ... 125	$^\circ\text{C}$
$V_{isol}$	AC sinus 50 Hz, $t = 1\text{ min}$	2500	V

Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
<b>Inverter - IGBT</b>					
$V_{CE(sat)}$	$I_C = 200\text{ A}$ $V_{GE} = 15\text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$	1.90	2.20	V
		$T_j = 150^\circ\text{C}$	2.30	2.60	V
$V_{CE0}$	chipelevel	$T_j = 25^\circ\text{C}$	0.80	0.90	V
		$T_j = 150^\circ\text{C}$	0.70	0.80	V
$r_{CE}$	$V_{GE} = 15\text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$	5.5	6.5	m $\Omega$
		$T_j = 150^\circ\text{C}$	8.0	9.0	m $\Omega$
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 8\text{ mA}$	5.2	5.8	6.4	V
$I_{CES}$	$V_{GE} = 0\text{ V}$ $V_{CE} = 1700\text{ V}$	$T_j = 25^\circ\text{C}$		0.3	mA
				-	mA
$C_{ies}$	$V_{CE} = 25\text{ V}$		16.00		nF
$C_{oes}$	$V_{GE} = 0\text{ V}$		0.68		nF
$C_{res}$			0.58		nF
$Q_G$	-8 V ... +15 V		1600		nC
$R_{Gint}$	$T_j = 25^\circ\text{C}$		3.8		$\Omega$
$t_{d(on)}$	$V_{CC} = 900\text{ V}$ $I_C = 200\text{ A}$		250		ns
$t_r$	$R_{G on} = 2\ \Omega$		46		ns
$E_{on}$	$R_{G off} = 2\ \Omega$		37		mJ
$t_{d(off)}$	$di/dt_{on} = 5844\text{ A}/\mu\text{s}$		652		ns
$t_f$	$di/dt_{off} = 1370\text{ A}/\mu\text{s}$ $dv/dt = 5134\text{ V}/\mu\text{s}$		177		ns
$E_{off}$	$V_{GE} = +15/-15\text{ V}$ $L_s = 25\text{ nH}$		66		mJ
$R_{th(j-s)}$	per IGBT, $\lambda_{paste} = 0.8\text{ W}/(\text{K}\cdot\text{m})$		0.23		K/W

# SKiiP 36GB17E4V1



MiniSKiiP® 3 Dual

## Half-Bridge

### SKiiP 36GB17E4V1

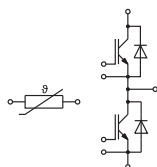
#### Features\*

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#### Remarks

- Max. case temperature limited to  $T_C=125^\circ\text{C}$
- Product reliability results valid for  $T_j \leq 150^\circ\text{C}$  (recommended  $T_{j,op} = -40 \dots +150^\circ\text{C}$ )

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
<b>Inverse - Diode</b>						
$V_F = V_{EC}$	$I_F = 200\text{ A}$ $V_{GE} = 0\text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$		2.00	2.40	V
		$T_j = 150^\circ\text{C}$		2.15	2.57	V
$V_{F0}$	chipelevel	$T_j = 25^\circ\text{C}$		1.32	1.56	V
		$T_j = 150^\circ\text{C}$		1.08	1.22	V
$r_F$	chipelevel	$T_j = 25^\circ\text{C}$		3.4	4.2	m $\Omega$
		$T_j = 150^\circ\text{C}$		5.4	6.8	m $\Omega$
$I_{RRM}$	$I_F = 200\text{ A}$			353		A
$Q_{rr}$	$di/dt_{off} = 6748\text{ A}/\mu\text{s}$			70		$\mu\text{C}$
$E_{rr}$	$V_{GE} = -15\text{ V}$ $V_{CC} = 900\text{ V}$			47		mJ
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=0.8\text{ W}/(\text{K}\cdot\text{m})$			0.32		K/W
<b>Module</b>						
$L_{CE}$				15		nH
$M_s$	to heat sink		2		2.5	Nm
$w$				76		g
<b>Temperature Sensor</b>						
$R_{100}$	$T_c=100^\circ\text{C}$ ( $R_{25}=5\text{ k}\Omega$ )			$493 \pm 5\%$		$\Omega$
$B_{25/85}$	$R_{(T)}=R_{25} \cdot \exp[B_{25/85} \cdot (1/T - 1/298)]$ , $T[\text{K}]$			3420		K



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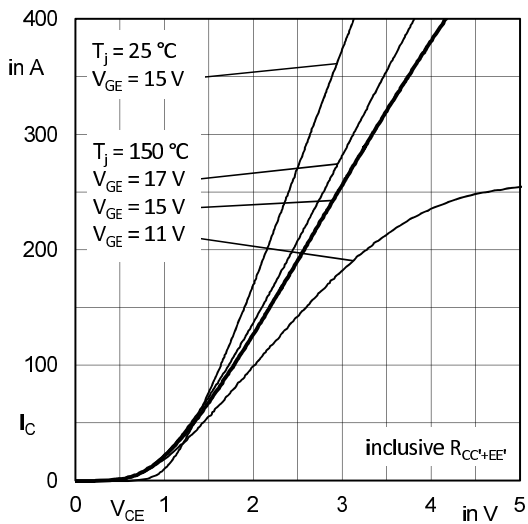


Fig. 1: Typ. output characteristic

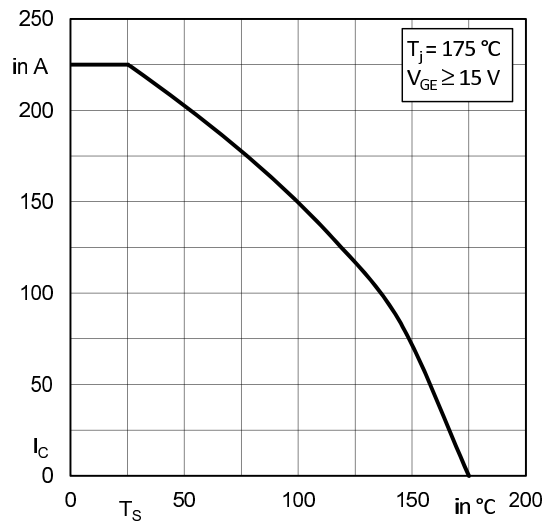


Fig. 2: Rated current vs. temperature  $I_c = f(T_s)$

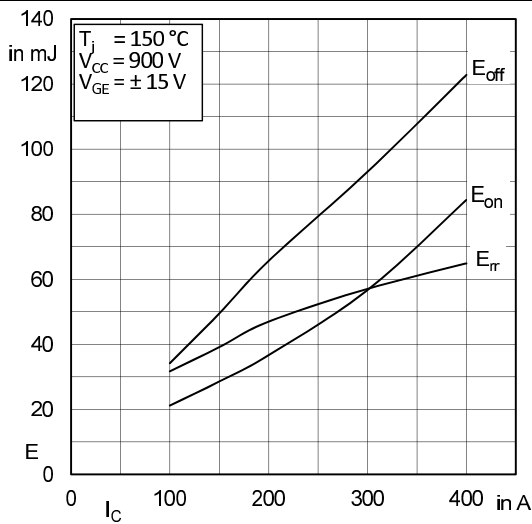


Fig. 3: Typ. turn-on /-off energy =  $f(I_c)$

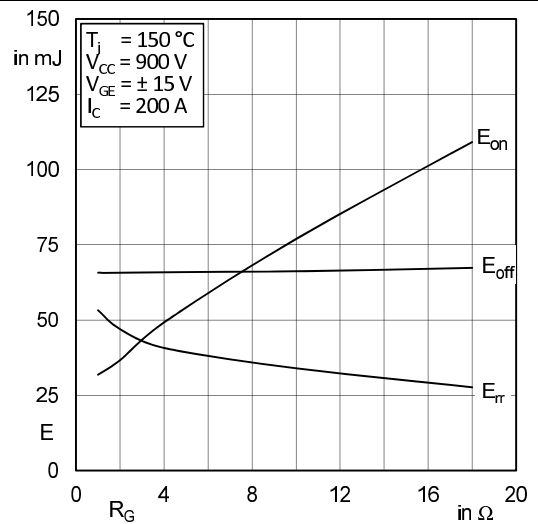


Fig. 4: Typ. turn-on /-off energy =  $f(R_G)$

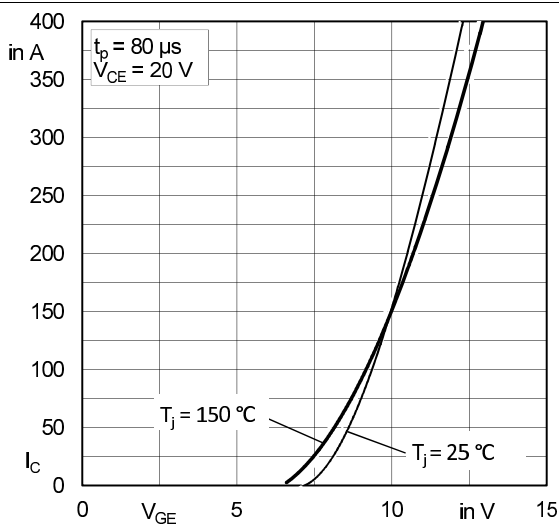


Fig. 5: Typ. transfer characteristic

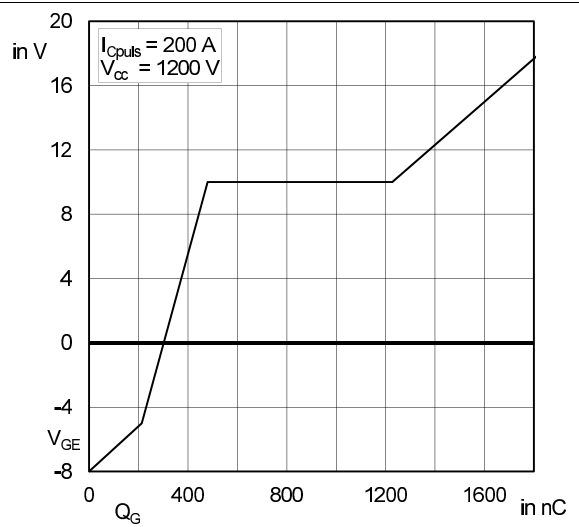


Fig. 6: Typ. gate charge characteristic

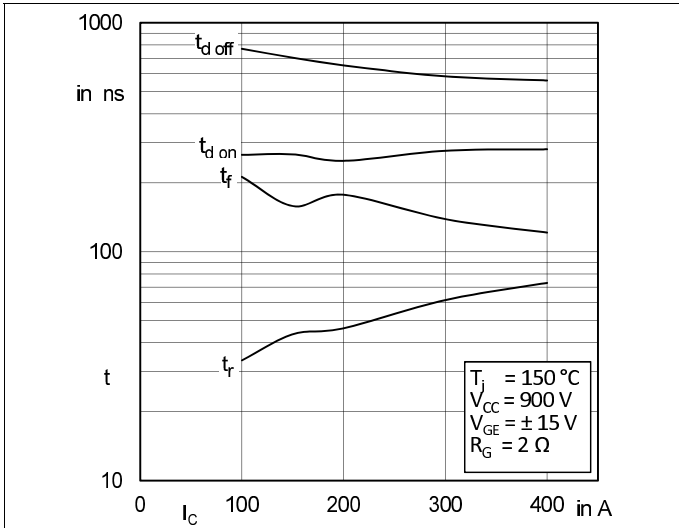


Fig. 7: Typ. switching times vs.  $I_C$

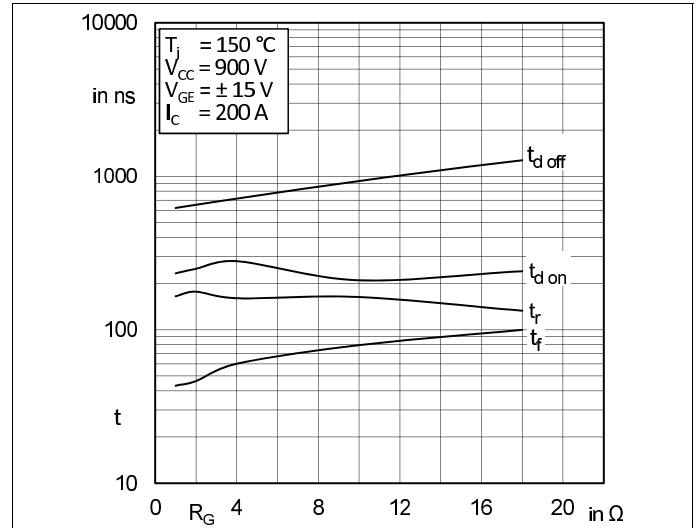


Fig. 8: Typ. switching times vs. gate resistor  $R_G$

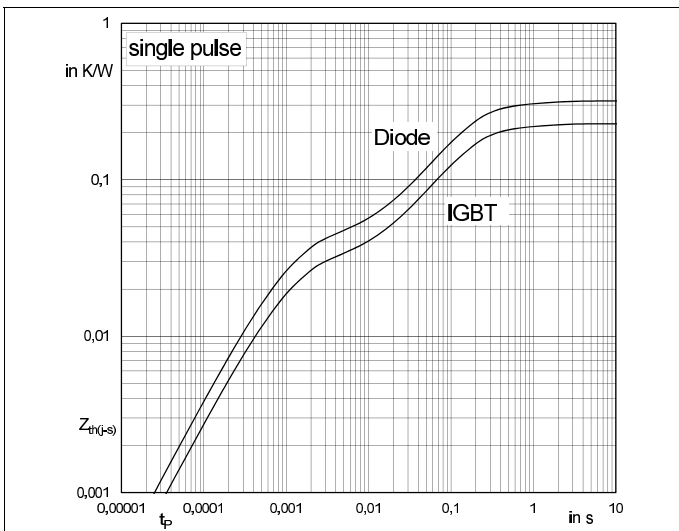


Fig. 9: Typ. transient thermal impedance

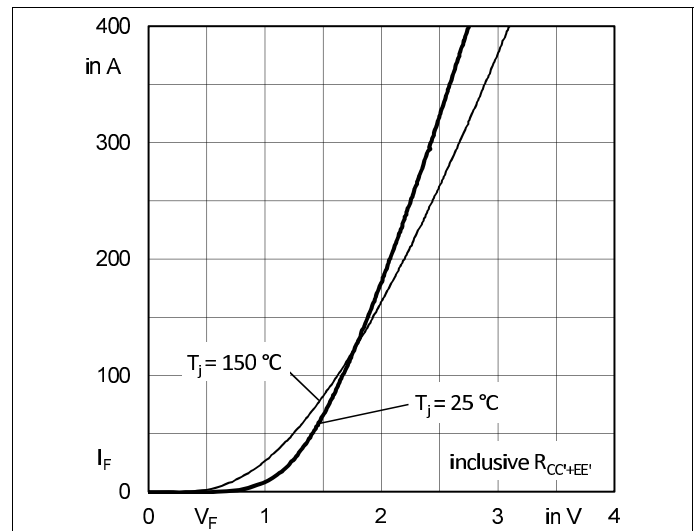


Fig. 10: Typ. CAL diode forward characteristic

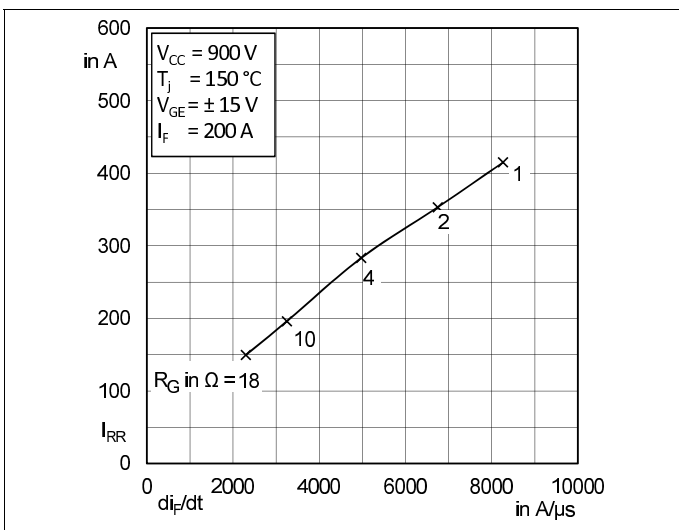


Fig. 11: Typ. CAL diode peak reverse recovery current

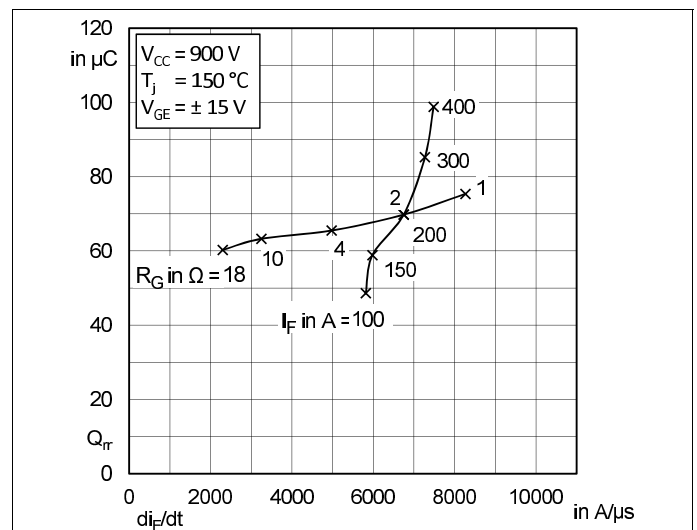
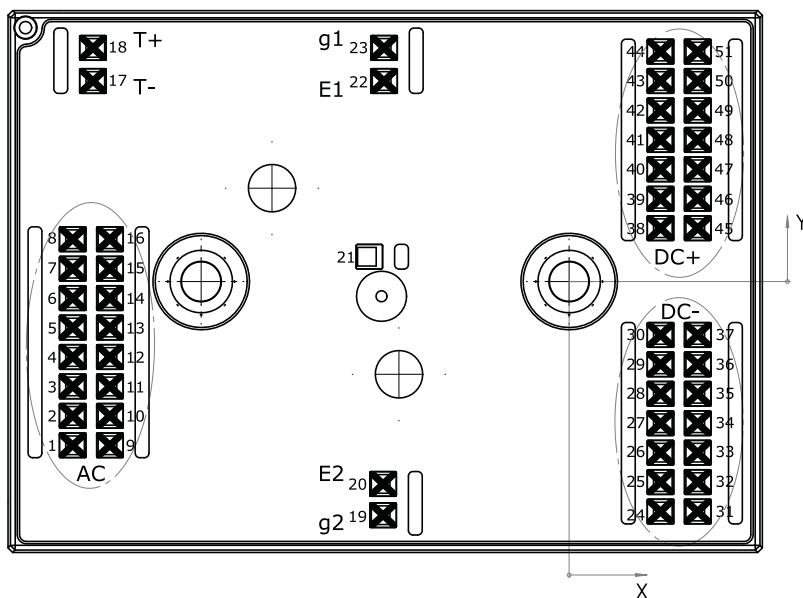


Fig. 12: Typ. CAL diode recovery charge

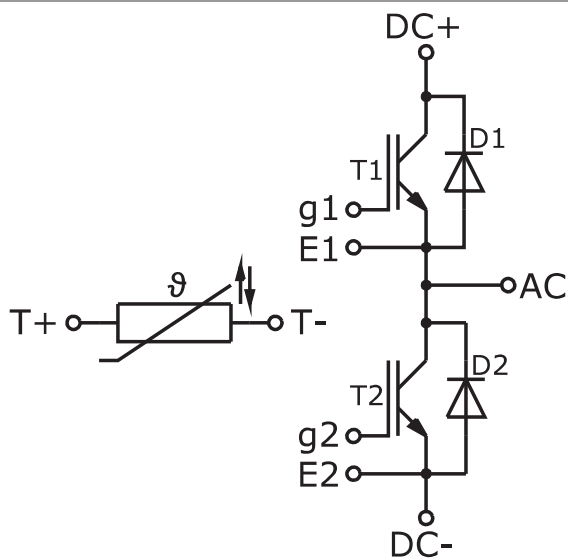
# SKiiP 36GB17E4V1

Pin out											
Pin	X	Y	Function	Pin	X	Y	Function	Pin	X	Y	Function
1	-53,98	-17,80	AC	18	-51,78	25,40	T+	35	13,98	-12,20	DC-
2	-53,98	-14,60	AC	19	-20,23	-25,40	g2	36	13,98	-9,00	DC-
3	-53,98	-11,40	AC	20	-20,23	-22,00	E2	37	13,98	-5,80	DC-
4	-53,98	-8,20	AC	21	-21,73	2,70		38	9,93	5,80	DC+
5	-53,98	-5,00	AC	22	-20,13	21,80	E1	39	9,93	9,00	DC+
6	-53,98	-1,80	AC	23	-20,13	25,40	g1	40	9,93	12,20	DC+
7	-53,98	1,40	AC	24	9,93	-25,00	DC-	41	9,93	15,40	DC+
8	-53,98	4,60	AC	25	9,93	-21,80	DC-	42	9,93	18,60	DC+
9	-49,93	-17,80	AC	26	9,93	-18,60	DC-	43	9,93	21,80	DC+
10	-49,93	-14,60	AC	27	9,93	-15,40	DC-	44	9,93	25,00	DC+
11	-49,93	-11,40	AC	28	9,93	-12,20	DC-	45	13,98	5,80	DC+
12	-49,93	-8,20	AC	29	9,93	-9,00	DC-	46	13,98	9,00	DC+
13	-49,93	-5,00	AC	30	9,93	-5,80	DC-	47	13,98	12,20	DC+
14	-49,93	-1,80	AC	31	13,98	-25,00	DC-	48	13,98	15,40	DC+
15	-49,93	1,40	AC	32	13,98	-21,80	DC-	49	13,98	18,60	DC+
16	-49,93	4,60	AC	33	13,98	-18,60	DC-	50	13,98	21,80	DC+
17	-51,78	21,80	T-	34	13,98	-15,40	DC-	51	13,98	25,00	DC+

all values in [mm]



Pinout and Dimensions



Pinout

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

## **\*IMPORTANT INFORMATION AND WARNINGS**

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